



Discription

Low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a DFN1006(SOD-882) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.



DFN1006-2L

Features

- ★ Bidirectional ESD protection of one line
- ★ Low operating voltage: 7.0V
- ★ Low clamping voltage $V_C = 13V @ 8A$
- ★ Response time is typically $< 1ns$
- ★ Ultra Low Leakage: nA level
- ★ IEC 61000-4-2: level 4 (ESD)
- ★ IEC 61000-4-5 (surge): IPPMQ 8A



Applications

- ★ Portable electronics
- ★ Computers and peripherals
- ★ Audio and video equipment
- ★ Cellular handsets and accessories
- ★ Communication systems
- ★ Power supplies

Circuit Diagram

Ordering information

Product ID	Pack	Qty(PCS)
AOZ8S507BDS-07	DFN1006-2L	10000



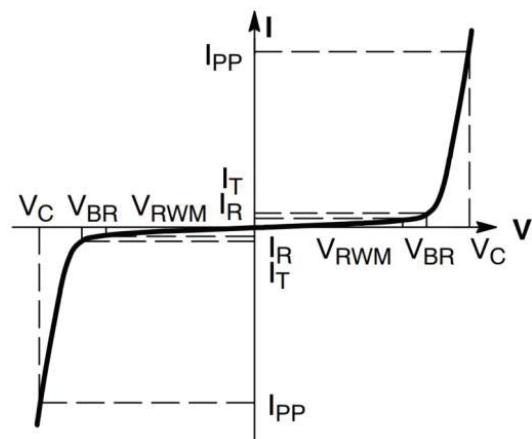
Absolute Ratings($T_{amb} = 25^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20\mu\text{s}$)	P_{PPM}	104	W
Maximum lead temperature for soldering during 10s	T_L	260	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Operating Temperature Range	T_{OP}	-40 to +125	$^{\circ}\text{C}$
Maximum junction temperature	T_j	150	$^{\circ}\text{C}$
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	20	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	15	kV

Electrical Characteristics

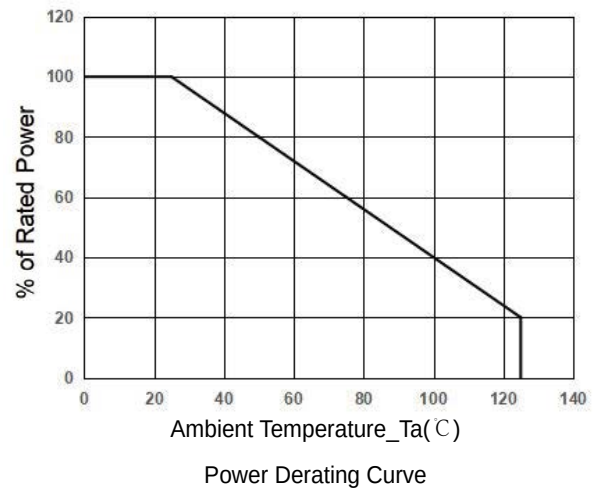
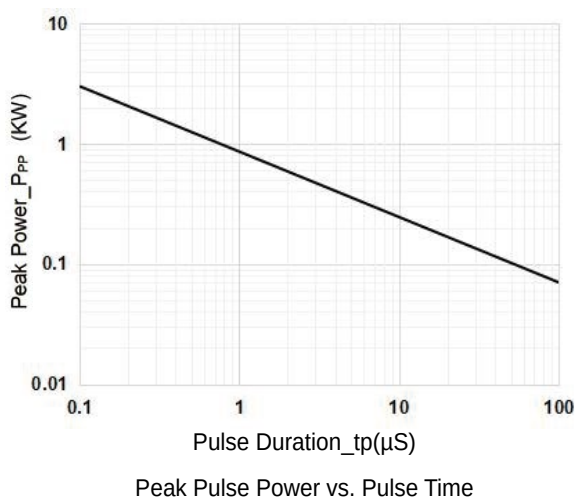
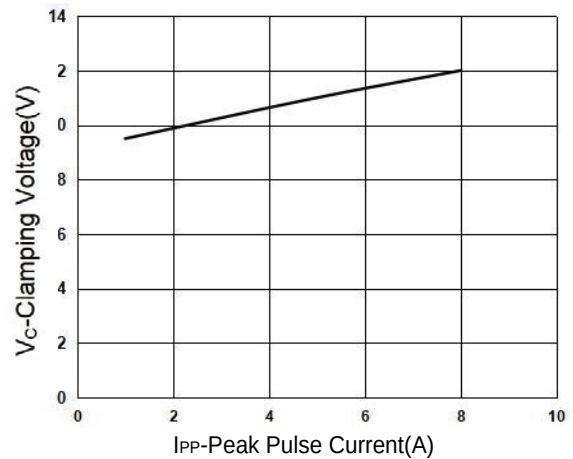
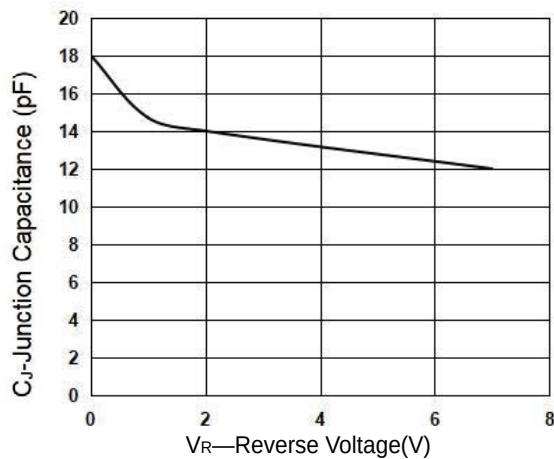
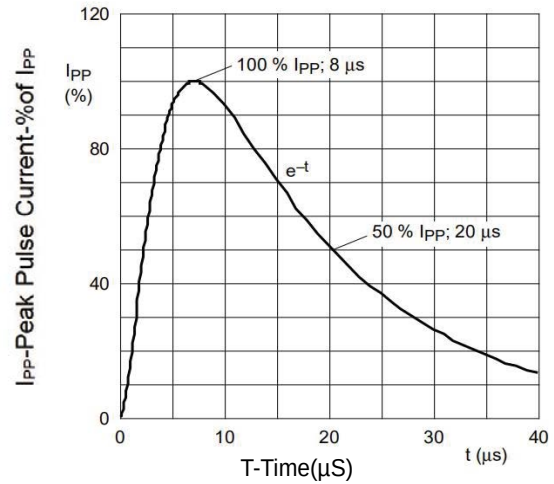
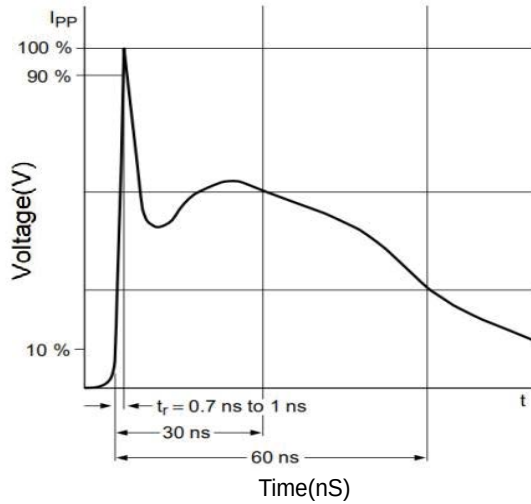
Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	7.0	V	
Breakdown Voltage	V_{BR}	7.6	8.2	9.0	V	$I_T=1\text{mA}$
Leakage Current I_{Leak}	I_R	--	--	0.1	nA	$V_{RWM}=7.0\text{V}$
Clamping Voltage	V_C	--	10.0	12.0	V	$I_{PP}=5\text{A}, t_p=8/20\mu\text{s}$
Clamping Voltage	V_C	--	11.5	13.0	V	$I_{PP}=8\text{A}, t_p=8/20\mu\text{s}$
Junction Capacitance	C_J	--	18.0	--	pF	$V_R=0\text{V}, f=1\text{MHz}$

Symbol	Parameter
I_{PPM}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Reverse Leakage Current @ V_{RWM}
I_T	Test Current
V_{BR}	Breakdown Voltage @ I_T



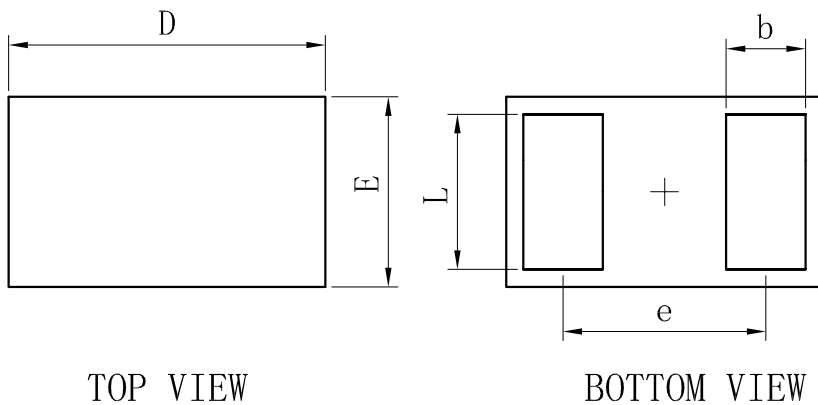


Typical Characteristics

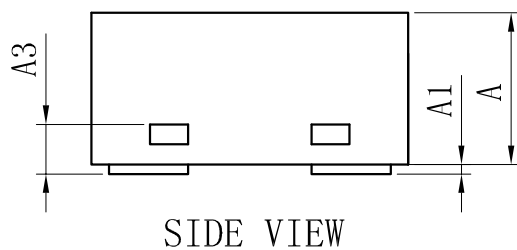




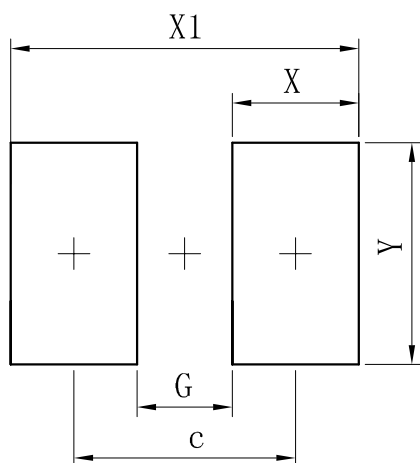
Outline And Dimensions



DFN1006-2L			
Dim	Min	Typ	Max
D	0.95	1.00	1.05
E	0.55	0.60	0.65
e	—	0.64	—
L	0.44	0.49	0.54
b	0.20	0.25	0.30
A	0.43	0.48	0.53
A1	0	—	0.05
A3	0.127REF.		
All Dimensions in mm			



Soledering Footprint



Dimensions	(mm)
c	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70



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